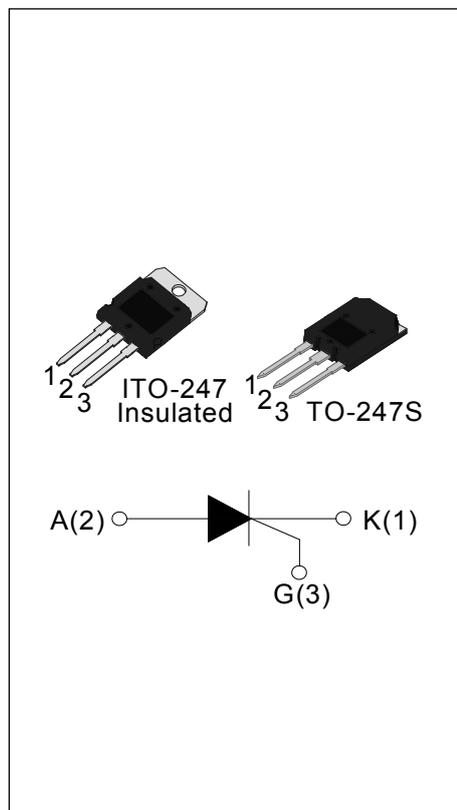




### DESCRIPTION:

With high ability to withstand the shock loading of large current, JCTxx110IS provides high dv/dt rate with high frequency noise immunity. Products are especially are commended for use on solid state relay, motorcycle, power charger, T-tools etc. From all three pins to external heatsink, JCTxx110IS provides an insulation voltage of 2500 V<sub>RMS</sub>, complying with UL standards (File ref: E252906). Package ITO-247 & TO-247S are RoHS compliant. (2011/65/EU)



### MAIN FEATURES

Symbol	Value	Unit
I <sub>T(RMS)</sub>	110	A
V <sub>DRM</sub> / V <sub>RRM</sub>	1200/1600	V
I <sub>GT</sub>	≤80	mA

### ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Storage junction temperature range		T <sub>stg</sub>	-40-150	°C
Operating junction temperature range		T <sub>j</sub>	-40-125	°C
Repetitive peak off-state voltage(T <sub>j</sub> =25°C)		V <sub>DRM</sub>	1200/1600	V
Repetitive peak reverse voltage(T <sub>j</sub> =25°C)		V <sub>RRM</sub>	1200/1600	V
RMS on-state current	ITO-247(Ins) (T <sub>c</sub> =80°C)	I <sub>T(RMS)</sub>	110	A
	TO-247S (T <sub>c</sub> =65°C)			
Non repetitive surge peak on-state current (t <sub>p</sub> =10ms)		I <sub>TSM</sub>	1300	A
I <sup>2</sup> t value for fusing (t <sub>p</sub> =10ms)		I <sup>2</sup> t	8450	A <sup>2</sup> s
Critical rate of rise of on-state current (I <sub>G</sub> =2 × I <sub>GT</sub> )		dI/dt	150	A/μs

Peak gate current	$I_{GM}$	4	A
Average gate power dissipation	$P_{G(AV)}$	1	W
Peak gate power	$P_{GM}$	5	W

**ELECTRICAL CHARACTERISTICS** ( $T_j=25^\circ\text{C}$  unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
$I_{GT}$	$V_D=12\text{V } R_L=33\Omega$	-	-	80	mA
$V_{GT}$		-	-	1.5	V
$V_{GD}$	$V_D=V_{DRM} T_j=125^\circ\text{C } R_L=3.3\text{K}\Omega$	0.25	-	-	V
$I_L$	$I_G=1.2I_{GT}$	-	-	250	mA
$I_H$	$I_T=1\text{A}$	-	-	150	mA
dV/dt	$V_D=2/3V_{DRM}$ Gate Open $T_j=125^\circ\text{C}$	1000	-	-	V/ $\mu\text{s}$

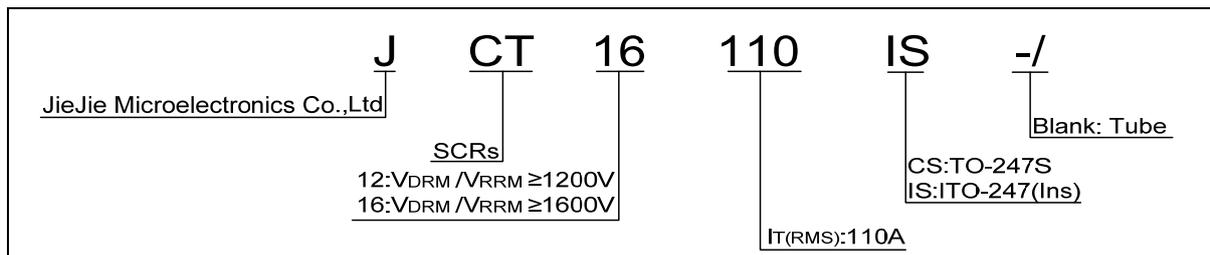
**STATIC CHARACTERISTICS**

Symbol	Parameter		Value(MAX)	Unit
$V_{TM}$	$I_{TM}=150\text{A } t_p=380\mu\text{s}$	$T_j=25^\circ\text{C}$	1.8	V
$V_{TO}$	Threshold voltage	$T_j=125^\circ\text{C}$	0.95	V
$R_D$	Dynamic resistance	$T_j=125^\circ\text{C}$	3.9	m $\Omega$
$I_{DRM}$	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25^\circ\text{C}$	50	$\mu\text{A}$
$I_{RRM}$		$T_j=125^\circ\text{C}$	10	mA

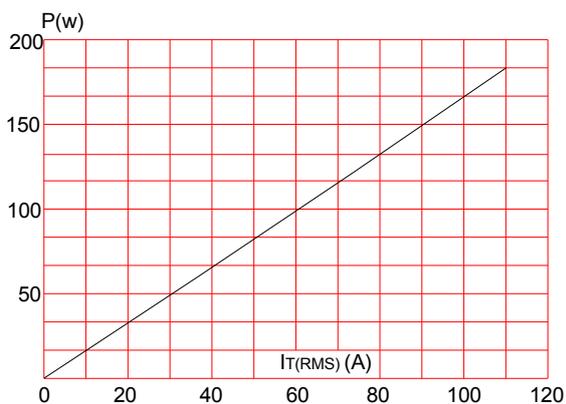
**THERMAL RESISTANCES**

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	junction to case(AC)	ITO-247(Ins)	0.41	$^\circ\text{C/W}$
		TO-247S	0.65	

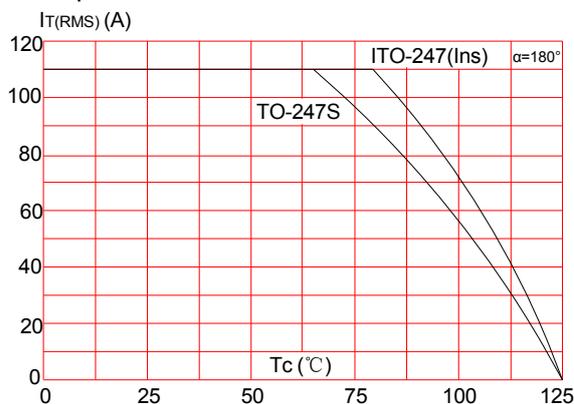
ORDERING INFORMATION



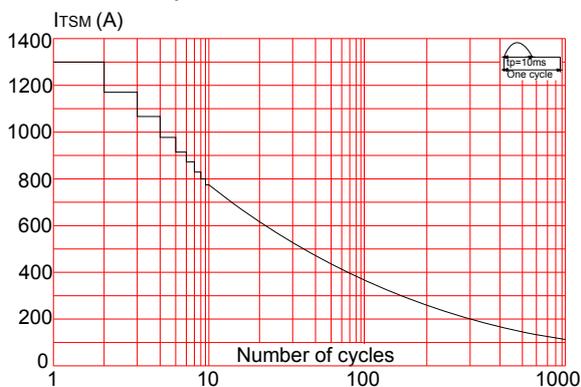
**FIG.1:** Maximum power dissipation versus RMS on-state current



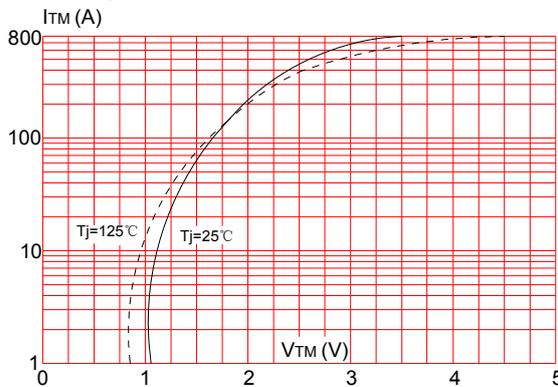
**FIG.2:** RMS on-state current versus case temperature



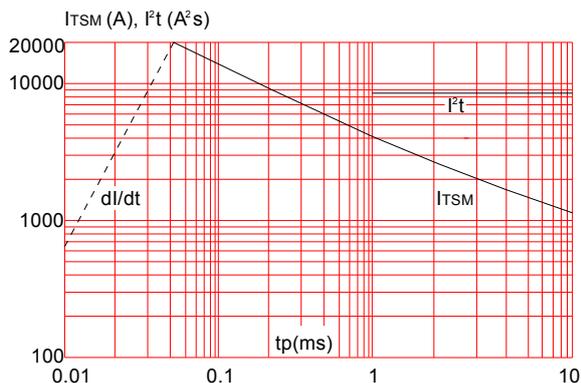
**FIG.3:** Surge peak on-state current versus number of cycles



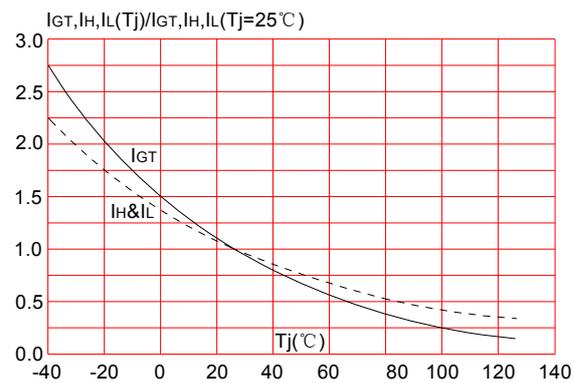
**FIG.4:** On-state characteristics (maximum values)



**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10ms$ , and corresponding value of  $I^2t$  ( $di/dt < 150A/\mu s$ )



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



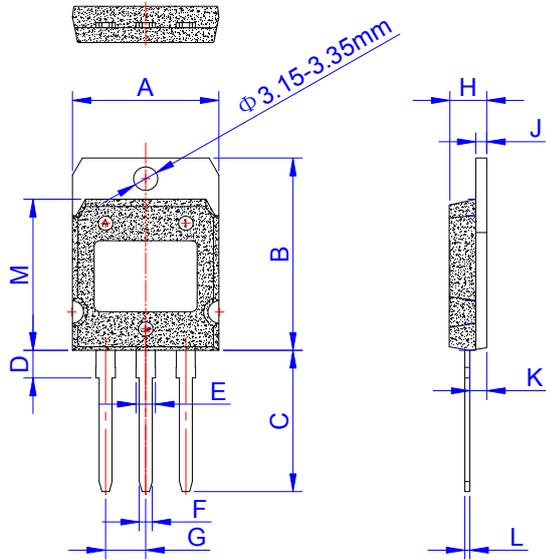
**ORDERING INFORMATION**

<b>Order code</b>	<b>Voltage V<sub>DRM</sub>/V<sub>RRM</sub> (V)</b>	<b>IGT(mA)</b>	<b>Package</b>	<b>Base qty. (pcs)</b>	<b>Delivery mode</b>
<b>JCT12110/16110IS</b>	<b>1200/1600</b>	<b>80</b>	<b>ITO-247</b>	<b>25</b>	<b>Tube</b>
<b>JCT12110/16110CS</b>			<b>TO-247S</b>	<b>30</b>	<b>Tube</b>

**Document Revision History**

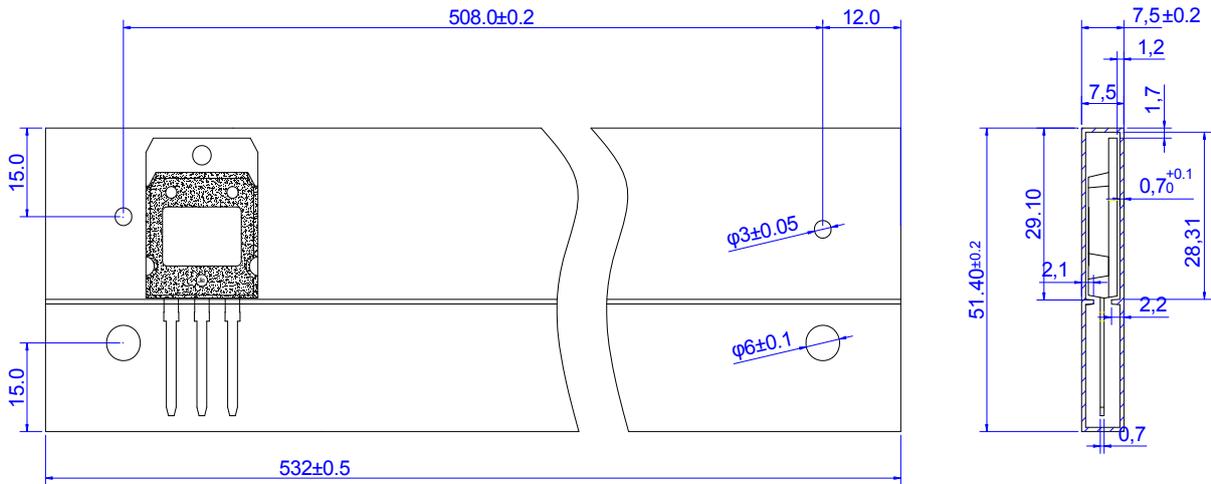
Date	Revision	Changes
April 27, 2021	2	Last update
June 22, 2021	3	Add $V_{TO}$ & $R_D$

PACKAGE MECHANICAL DATA



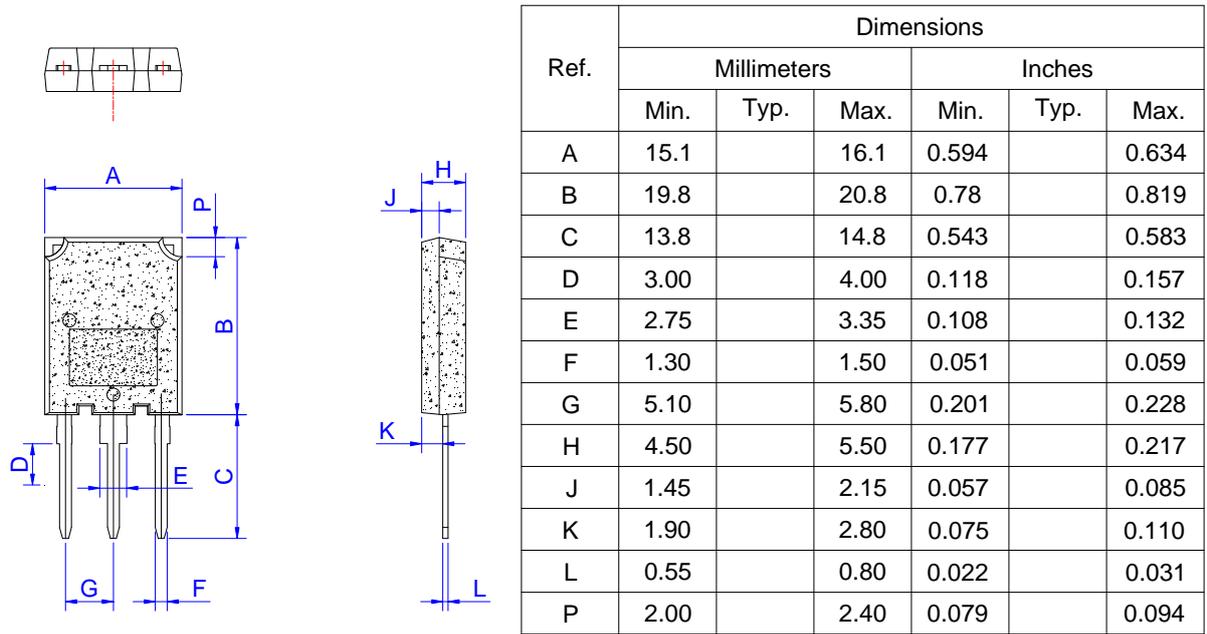
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	19.7	19.9	20.1	0.776	0.783	0.791
B	26.9	27.1	27.3	1.059	1.067	1.075
C	19.4	19.9	20.4	0.764	0.783	0.803
D	3.80	3.90	4.00	0.150	0.154	0.157
E	2.56	2.66	2.76	0.101	0.105	0.109
F	1.66	1.76	1.86	0.065	0.069	0.073
G		5.45			0.215	
H	5.05	5.10	5.50	0.199	0.201	0.217
J	1.45	1.50	1.55	0.057	0.059	0.061
K	2.20	2.30	2.40	0.087	0.091	0.094
L	0.60	0.70	0.80	0.024	0.028	0.031
M	21.2	21.3	21.4	0.835	0.839	0.843

DELIVERY MODE

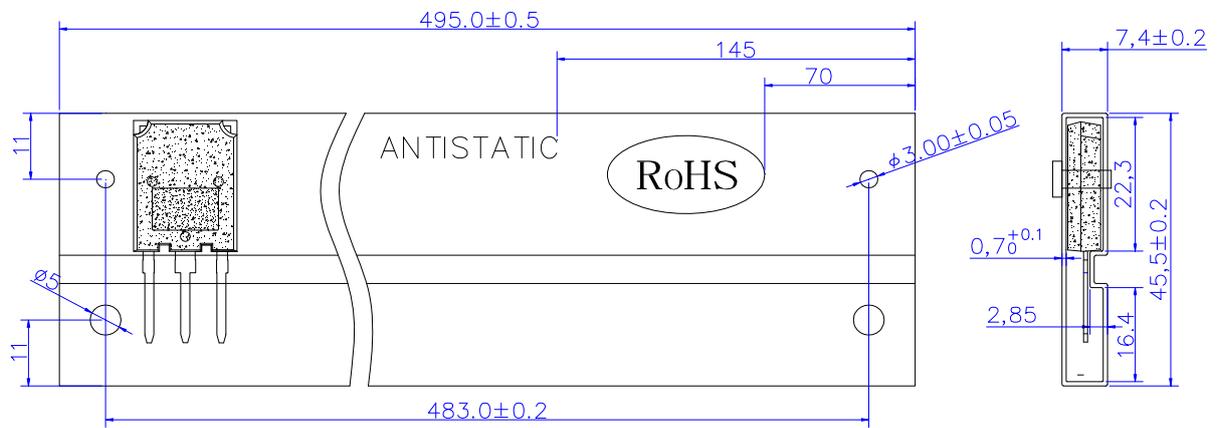


PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
ITO-247	TUBE	25	400	1,600

PACKAGE MECHANICAL DATA



DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-247S	TUBE	30	450	2,250



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